**TENTATIVE** 

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# **HN9C14FT**

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

• Two devices are built in to the super-thin and ultra super mini (6pins) package: TU6

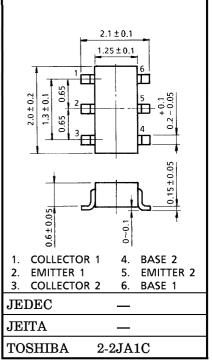
#### **MOUNTED DEVICES**

	Q1	Q2
Three-pins (SSM) mold products are corresponded.	2SC5066	2SC5066

#### MAXIMUM RATINGS (Ta = 25°C)

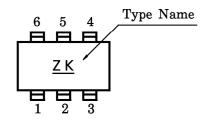
CHARACTERISTIC	SYMBOL	Q1 / Q2	UNIT
Collector-Base Voltage	$v_{\mathrm{CBO}}$	20	V
Collector-Emitter Voltage	$V_{CEO}$	12	V
Emitter-Base Voltage	$V_{ m EBO}$	3	V
Collector Current	$I_{\mathbb{C}}$	30	mA
Base Current	$I_{\mathbf{B}}$	15	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	200	mW
Junction Temperature	Tj	125	°C
Storage Temperature Range	$ m T_{stg}$	-55~125	°C

Unit in mm

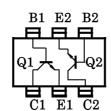


Weight: 0.008g

### **MARKING**



PIN ASSIGNMENT (TOP VIEW)



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## ELECTRICAL CHARACTERISTICS Q1 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	$\mu$ A
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=1V, I_C=0$	_	_	1	$\mu$ A
DC Current Gain	${ m h_{FE}}$	$V_{CE}=5V$ , $I_{C}=10mA$	80	_	240	_
Transition Frequency	$ m f_{T}$	$V_{CE}=5V, I_{C}=10mA$	5	7	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE} = 5V, I_{C} = 10mA, f = 500MHz$	_	16	_	dB
	$ S_{21e} ^2$ (2)	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=1000MHz	8	11	_	dB
Noise Figure	NF (1)	$V_{CE} = 5V, I_{C} = 3mA, f = 500MHz$	_	1	_	dB
	NF (2)	$V_{CE}=5V$ , $I_{C}=3mA$ , $f=1000MHz$	_	1.1	2	dB

## ELECTRICAL CHARACTERISTICS Q2 (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 10V, I_{E} = 0$	_	_	1	$\mu$ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_{C}=0$	_		1	$\mu$ A
DC Current Gain	$_{ m h_{FE}}$	$V_{CE}=5V$ , $I_{C}=10mA$	80	_	240	_
Transition Frequency	$\mathbf{f_T}$	$V_{CE}=5V$ , $I_{C}=10mA$	5	7	_	GHz
Insertion Gain	$ S_{21e} ^2$ (1)	$V_{CE} = 5V, I_{C} = 10mA, f = 500MHz$	_	16	_	dB
	$ S_{21e} ^2$ (2)	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=1000MHz	8	11	_	dB
Noise Figure	NF (1)	$V_{CE}=5V$ , $I_{C}=3mA$ , $f=500MHz$		1	_	dB
	NF (2)	$V_{CE} = 5V, I_{C} = 3mA, f = 1000MHz$	_	1.1	2	dB

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